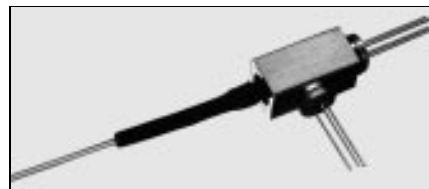


## BIDI™ Transceiver Optical Module 1300/1300 nm, Medium Power

**SBM 51214X**

- Designed for application in passive-optical networks
- Integrated beam splitter
- Bidirectional Transmission in one optical window
- Laser diode with Multi-Quantum Well structure
- Suitable for bit rates up to 1 Gbit/s
- Ternary Photodiode at rear mirror for monitoring and control of radiant power
- Low noise/high bandwidth PIN diode
- Hermetically sealed subcomponents, similar to TO 18
- With singlemode fiber pigtail



| Type       | Ordering Code | Connector |
|------------|---------------|-----------|
| SBM 51214A | Q62702-Pxxxx  | DIN       |
| SBM 51214G | Q62702-Pxxxx  | FC / PC   |

**Component with other connector types on request.**

### Maximum Ratings

Output power ratings refer to the optical port. The operating temperature of the submount is identical to the case temperature.

| Parameter | Symbol | Values | Unit |
|-----------|--------|--------|------|
|-----------|--------|--------|------|

### Module

|                                                                                   |           |               |    |
|-----------------------------------------------------------------------------------|-----------|---------------|----|
| Operating temperature range at case                                               | $T_C$     | – 40 ... + 85 | °C |
| Storage temperature range                                                         | $T_{stg}$ | – 40 ... + 85 | °C |
| Soldering temperature<br>$t_{max} = 30$ s, 2 mm distance from bottom edge of case | $T_S$     | 260           | °C |

### Laser Diode

|                  |              |     |    |
|------------------|--------------|-----|----|
| Forward current  | $I_{F\ max}$ | 150 | mA |
| Radiant power CW | $\Phi_e$     | 2   | mW |
| Reverse voltage  | $V_{R\ max}$ | 2   | V  |

## Maximum Ratings (cont'd)

| Parameter | Symbol | Values | Unit |
|-----------|--------|--------|------|
|-----------|--------|--------|------|

### Monitor Diode

|                 |              |    |    |
|-----------------|--------------|----|----|
| Forward current | $I_{F \max}$ | 2  | mA |
| Reverse voltage | $V_{R \max}$ | 10 | V  |

### PIN Photodiode

|                                             |                          |     |    |
|---------------------------------------------|--------------------------|-----|----|
| Forward current                             | $I_{F \max}$             | 2   | mA |
| Reverse voltage                             | $V_{BR}$                 | 10  | V  |
| Maximum optical power into the optical port | $\Phi_{\text{port max}}$ | 1.5 | mW |

## Characteristics

All optical data refer to the optical port,  $T_C = 25^\circ\text{C}$ .

| Parameter | Symbol | Values | Unit |
|-----------|--------|--------|------|
|-----------|--------|--------|------|

### Laser Diode

|                                                                         |                 |               |               |
|-------------------------------------------------------------------------|-----------------|---------------|---------------|
| Optical output power                                                    | $\Phi_e$        | > 1.2         | mW            |
| Emission wavelength center of range<br>$\Phi_e = 0.5 \text{ mW}$        | $\lambda$       | 1270 ... 1350 | nm            |
| Spectral bandwidth $\Phi_e = 0.5 \text{ mW}$ (RMS)                      | $\Delta\lambda$ | 5             | nm            |
| Threshold current ( $-40 \dots +85^\circ\text{C}$ )                     | $I_{th}$        | 2 ... 45      | mA            |
| Forward voltage $\Phi_e = 0.5 \text{ mW}$                               | $V_F$           | < 1.5         | V             |
| Radiant power at $I_{th}$                                               | $\Phi_{eth}$    | < 50          | $\mu\text{W}$ |
| Current above threshold at $25^\circ\text{C}$ , $\Phi_e = 1 \text{ mW}$ | $\Delta I_F$    | 10 ... 35     | mA            |
| Current above threshold, $\Phi_e = 1 \text{ mW}$                        | $\Delta I_F$    | 7 ... 50      | mA            |
| Variation of 1st derivative of P/I (0.1 ... 1 mW)                       | $dP/dI$         | -30 ... 30    | %             |
| Differential series resistance                                          | $r_S$           | < 8           | $\Omega$      |
| Rise and fall time (10 % - 90 %)                                        | $t_r, t_f$      | < 1           | ns            |
| Temperature coefficient of wavelength                                   | $TC_\lambda$    | < 0.5         | nm / K        |

Characteristics (cont'd)

| Parameter | Symbol | Values | Unit |
|-----------|--------|--------|------|
|-----------|--------|--------|------|

Monitor Diode

|                                                                          |       |              |               |
|--------------------------------------------------------------------------|-------|--------------|---------------|
| Dark current, $V_R = 2 \text{ V}$ , $\Phi_e = 0$ , $T_C = 85 \text{ °C}$ | $I_R$ | 200          | nA            |
| Photocurrent, $V_R = 2 \text{ V}$ , $\Phi_e = 0.5 \text{ mW}$            | $I_P$ | 100 ... 1000 | $\mu\text{A}$ |
| Capacitance, $V_R = 2 \text{ V}$ , $f = 1 \text{ MHz}$                   | $C_2$ | < 10         | pF            |
| Tracking error, $V_R = 2 \text{ V}$ ( <b>see note 1</b> )                | $TE$  | – 1 ... 1    | dB            |

Detector

|                                                                          |               |        |       |
|--------------------------------------------------------------------------|---------------|--------|-------|
| Dark current, $V_R = 2 \text{ V}$ , $\Phi_e = 0$ , $T_C = 85 \text{ °C}$ | $I_R$         | < 50   | nA    |
| Spectral sensitivity, $V_R = 2 \text{ V}$ , $\lambda = 1300 \text{ nm}$  | $S_\lambda$   | > 0.30 | A / W |
| Capacitance, $V_R = 2 \text{ V}$ , $f = 1 \text{ MHz}$                   | $C_2$         | < 1.5  | pF    |
| Rise and fall time, $V_R = 2 \text{ V}$ , 10 % – 90 %                    | $t_r$ , $t_f$ | < 1    | ns    |

Module

|                                         |       |        |    |
|-----------------------------------------|-------|--------|----|
| Optical crosstalk ( <b>see note 2</b> ) | $CRT$ | < – 22 | dB |
|-----------------------------------------|-------|--------|----|

**Note 1:** The tracking error  $TE$  is the variation rate of  $\Phi_e$  at constant current  $I_{\text{mon}}$  over a specified temperature range and relative to the reference point:  
 $I_{\text{mon,ref}} = I_{\text{mon}}(T = 25 \text{ °C}, \Phi_e = 0.5 \text{ mW})$ . Thus,  $TE$  is given by:

$$TE[\text{dB}] = 10 \times \log \frac{\Phi_e[T_C] - \Phi_e[25 \text{ °C}]}{\Phi_e[25 \text{ °C}]}$$

**Note 2:** Optical Crosstalk is defined as  $CRT = 10 \times \log (I_{\text{Det},0}/I_{\text{Det},1})$  with:  $I_{\text{Det},0}$  the photocurrent with  $\Phi_e = 0.5 \text{ mW}$  CW laser operation,  $V_R = 2 \text{ V}$ , with minimum optical return loss from fiber end and  $I_{\text{Det},1}$  the photocurrent without  $\Phi_e$ , but  $0.5 \text{ mW}$  optical input power,  $\lambda = 1300 \text{ nm}$ .

## Accompanying Information

$T = 25\text{ °C}$ : Threshold current, current above threshold for 1 mW output power, monitor current for 0.5 mW output power, peak wavelength.  
 $T = 85\text{ °C}$ : Threshold current, current above threshold for 1 mW output power, monitor current for 0.5 mW output power.

## End of Life Values

| Parameter                                                                                                                             | Symbol       | Value         | Unit |
|---------------------------------------------------------------------------------------------------------------------------------------|--------------|---------------|------|
| Threshold current at $T = 85\text{ °C}$                                                                                               | $I_{th}$     | < 60          | mA   |
| Current above threshold, over full temperature range, at $I_{mon,ref} = I_{mon}$ ( $T = 25\text{ °C}$ , $\Phi_e = 1\text{ mW}$ , BOL) | $\Delta I_F$ | 7 ... 70      | mA   |
| Tracking error ( <b>see note 1</b> )                                                                                                  | $TE$         | – 1.5 ... 1.5 | dB   |
| Detector dark current, $V_R = 2\text{ V}$ , $T = 85\text{ °C}$                                                                        | $I_R$        | < 200         | nA   |
| Monitor dark current, $V_R = 2\text{ V}$ , $T = 85\text{ °C}$                                                                         | $I_R$        | < 1           | μA   |

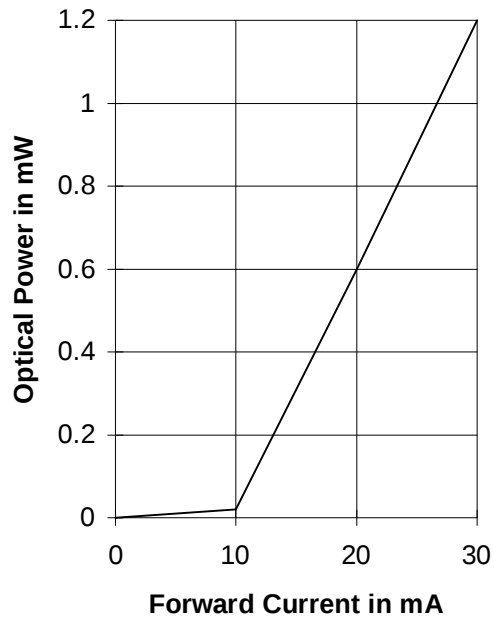
## Fiber Pigtail

Type: single mode, silica

| Parameter                               | Value         | Unit |
|-----------------------------------------|---------------|------|
| Mode field diameter                     | $9 \pm 1$     | μm   |
| Cladding diameter                       | $125 \pm 2$   | μm   |
| Mode field/cladding concentricity error | < 1           | μm   |
| Cladding non-circularity                | < 2           | %    |
| Mode field non-circularity              | < 6           | %    |
| Cut-off wavelength                      | > 1270        | nm   |
| Jacket diameter                         | $0.9 \pm 0.1$ | mm   |
| Bending radius                          | > 30          | mm   |
| Tensile strength fiber/case             | > 5           | N    |
| Length                                  | $1 \pm 0.2$   | m    |

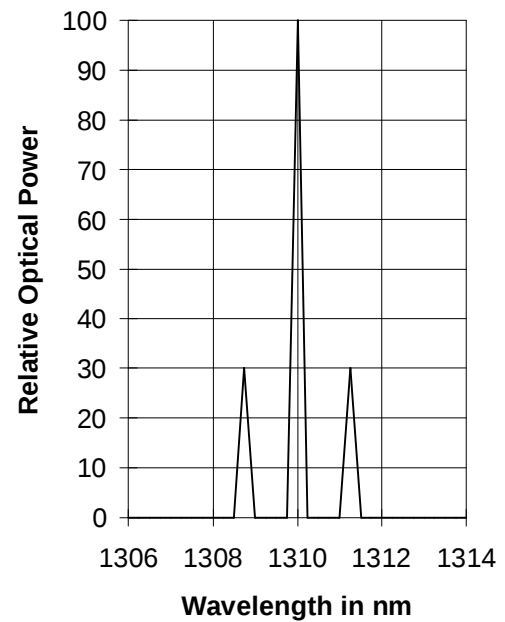
## Laser Diode

Radiant Power in Singlemode Fiber



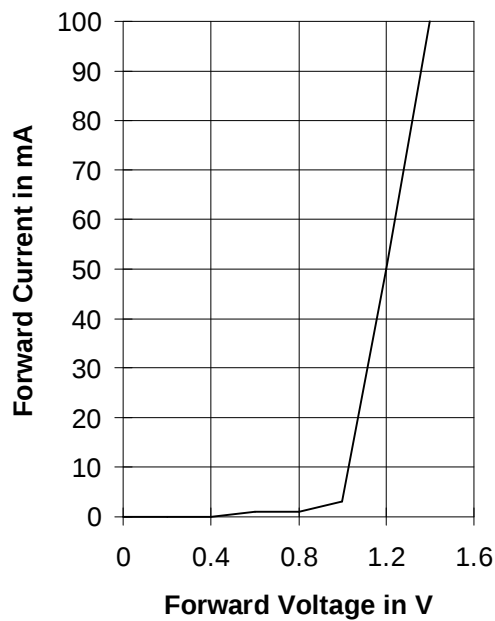
## Relative Radiant Power

$$\Phi_e = f(\lambda)$$



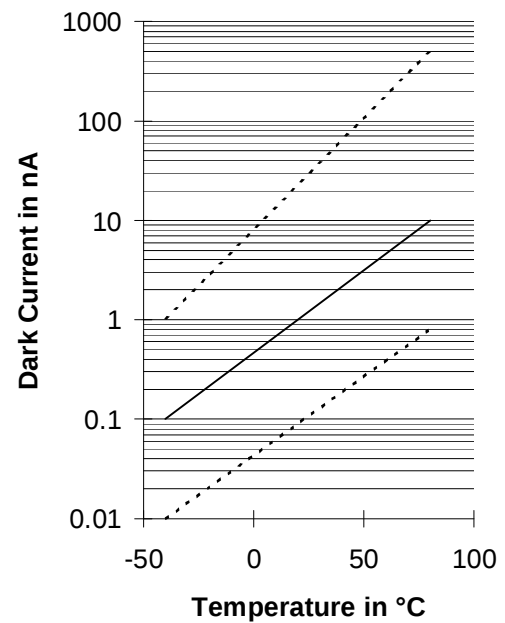
## Laser Forward Current

$$I_F = f(V_F)$$

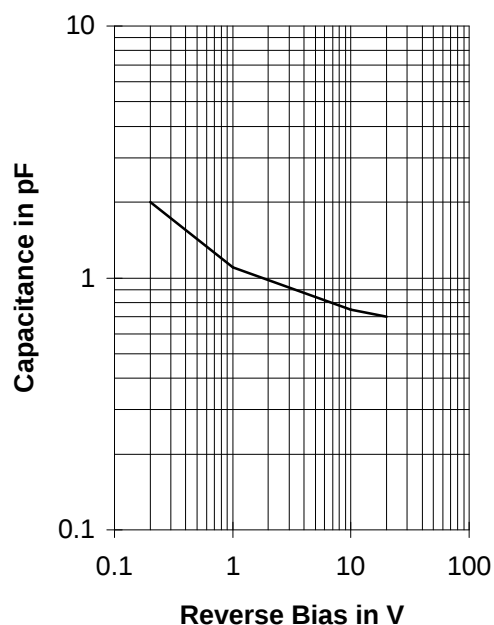


## Monitor Diode Dark Current $I_R = f(T_A)$

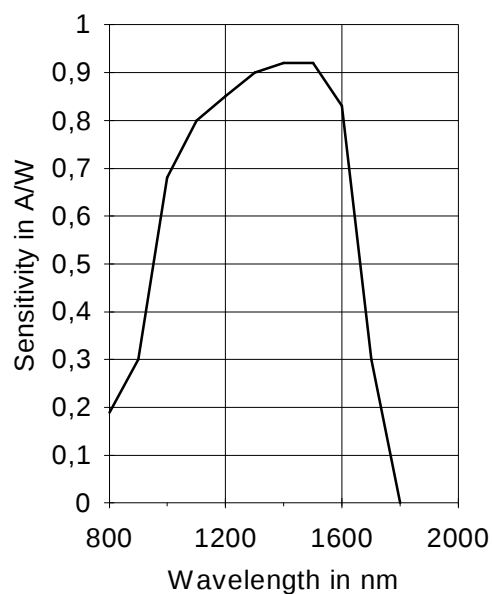
$$\Phi_{\text{port}} = 0, V_R = 5 \text{ V}$$



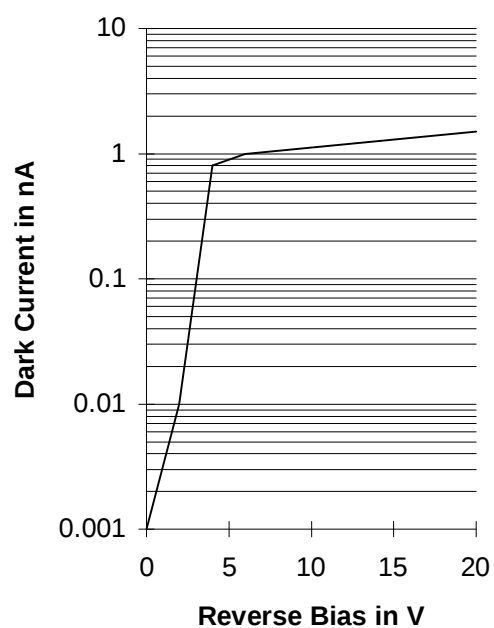
**Capacitance of PIN Diode  $C = f(V_R)$**   
 $\Phi_{\text{port}} = 0, f = 1 \text{ MHz}$



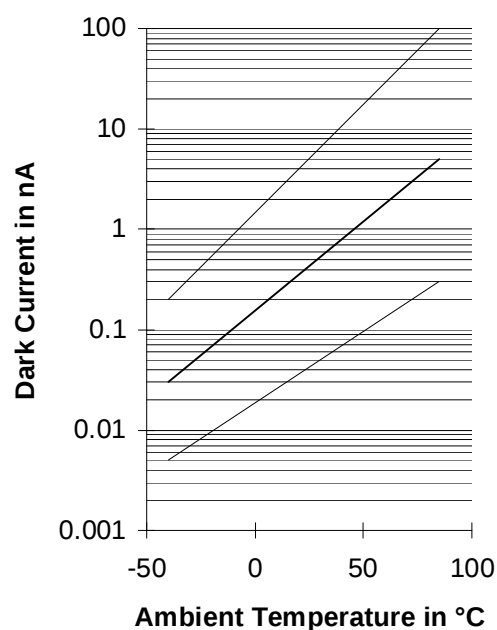
**Rel. Spectral Sensitivity of PIN Diode**  
 $V_R = 5 \text{ V}$



**Dark Current of PIN Diode  $I_R = f(V_R)$**   
 $I_F = f(V_F)$



**Dark Current of PIN Diode  $I_R = f(T_A)$**   
 $\Phi_{\text{port}} = 0, V_R = 5 \text{ V}$



Technical drawing of the SMF-1000 optical fiber pigtail assembly, showing dimensions and component labels.

**Top View Dimensions:**

- Overall width: 17.2
- Inner width: 15.2
- Pin spacing: 2.54 mm
- Pin 1 to center: 9.3
- Pin 2 to center: 8.0
- Pin 3 to center: 20.5
- Pin 1 to pin 3: 17.5
- Overall length: 36.0
- Inner length: 32.0
- Note:  $\phi 6$  max

**Side View Dimensions:**

- Overall length: 56.6
- Inner length: 48.6
- Pin 1 to center: 7.2
- Pin 2 to center: 6.7
- Pin 3 to center: 7.2
- Pin 1 to pin 3: 6.7
- Pin 1 to pin 3: 0.55
- Pin 1 to pin 3: 0.4

**Bottom View Dimensions:**

- Overall width: 8.2
- Inner width: 7.7
- Pin 1 to center: 8.2
- Pin 2 to center: 7.7
- Pin 3 to center: 11.5
- Pin 1 to pin 3: 9.5
- Pin spacing: 2.54 mm

**Component Labels:**

- Transmitter-Cathode
- Receiver-Anode
- SMF  $\phi 9/125/900 \mu\text{m}$  Pigtail length  $1000 \pm 200$

**Schematic Diagram:**

- Transmitter:** LD (Laser Diode) and MD (Modulator Diode) components.
- Receiver:** LD (Laser Diode) and MD (Modulator Diode) components.

**SBM 51214X**